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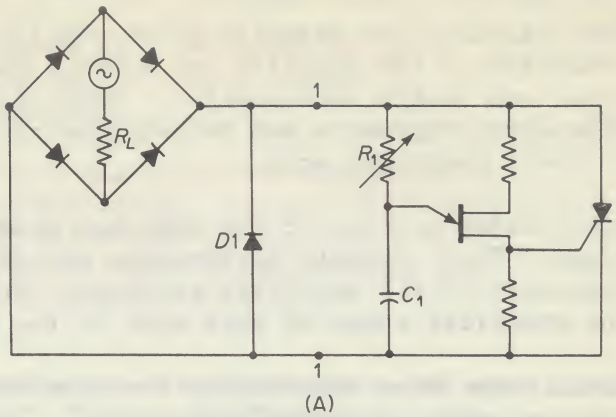

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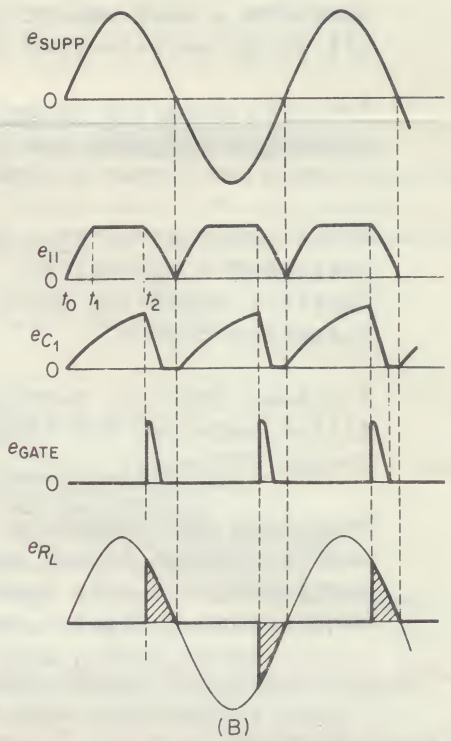

(B)

Fig. 15.27 (A) A-C phase-control circuit using a silicon-control rectifier. (B) Pertinent circuit waveforms.

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Gives material on bias networks which is truly useful for designing a circuit for any given operating point with specific operating point controls in case of transistor parameter change.

Provides complete material on power supplies. Explains filter networks and regulated supplies and gives meaningful design criteria.

Discusses very complete graphical techniques as a tool for handling large signal amplifier design. These techniques supplement key math equations to any large signal amplifier requirement - Class A single ended or Class AB push-pull.

PLUS, with the aid of this book, you will be able to:

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crystal clear. He has taught transistor courses to professional people at the General Electric Co. and has also taught at Mohawk Valley Community College, Utica, New York for five years.

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